

## FEATURES

- Member of the Texas Instruments Widebus+™ Family
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max  $t_{pd}$  of 1.8 ns at 1.8 V

- Low Power Consumption, 40- $\mu$ A Max  $I_{CC}$
- $\pm 8$ -mA Output Drive at 1.8 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## DESCRIPTION/ORDERING INFORMATION

This 32-bit buffer/driver is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUCH32244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as eight 4-bit buffers, four 8-bit buffers, two 16-bit buffers, or one 32-bit buffer. It provides true outputs and symmetrical active-low output-enable ( $\overline{OE}$ ) inputs.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

## ORDERING INFORMATION

$T_A$	PACKAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	LFBGA – GKE	SN74AUCH32244GKER	MK244

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

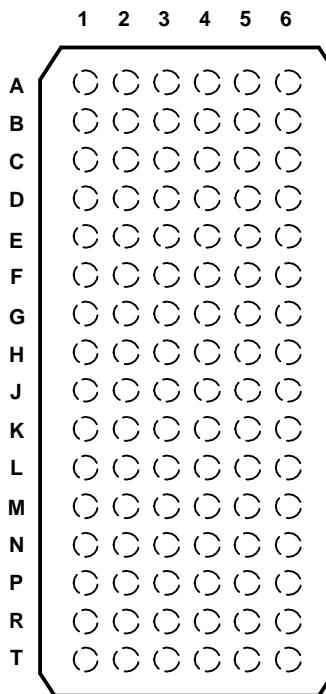
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**SN74AUCH32244**  
**32-BIT BUFFER/DRIVER**  
**WITH 3-STATE OUTPUTS**

SCES412B—SEPTEMBER 2002—REVISED JUNE 2005

 **TEXAS**  
**INSTRUMENTS**  
[www.ti.com](http://www.ti.com)

**GKE PACKAGE**  
**(TOP VIEW)**



**TERMINAL ASSIGNMENTS**

	1	2	3	4	5	6
<b>A</b>	1Y2	1Y1	$\bar{OE}$	$\bar{OE}$	1A1	1A2
<b>B</b>	1Y4	1Y3	GND	GND	1A3	1A4
<b>C</b>	2Y2	2Y1	$V_{CC}$	$V_{CC}$	2A1	2A2
<b>D</b>	2Y4	2Y3	GND	GND	2A3	2A4
<b>E</b>	3Y2	3Y1	GND	GND	3A1	3A2
<b>F</b>	3Y4	3Y3	$V_{CC}$	$V_{CC}$	3A3	3A4
<b>G</b>	4Y2	4Y1	GND	GND	4A1	4A2
<b>H</b>	4Y3	4Y4	$\bar{OE}$	$\bar{OE}$	4A4	4A3
<b>J</b>	5Y2	5Y1	$\bar{OE}$	$\bar{OE}$	5A1	5A2
<b>K</b>	5Y4	5Y3	GND	GND	5A3	5A4
<b>L</b>	6Y2	6Y1	$V_{CC}$	$V_{CC}$	6A1	6A2
<b>M</b>	6Y4	6Y3	GND	GND	6A3	6A4
<b>N</b>	7Y2	7Y1	GND	GND	7A1	7A2
<b>P</b>	7Y4	7Y3	$V_{CC}$	$V_{CC}$	7A3	7A4
<b>R</b>	8Y2	8Y1	GND	GND	8A1	8A2
<b>T</b>	8Y3	8Y4	$\bar{OE}$	$\bar{OE}$	8A4	8A3

**FUNCTION TABLE**  
**(EACH 4-BIT BUFFER)**

INPUTS		OUTPUT Y
$\bar{OE}$	A	
L	H	H
L	L	L

**FUNCTION TABLE  
(EACH 4-BIT BUFFER) (continued)**

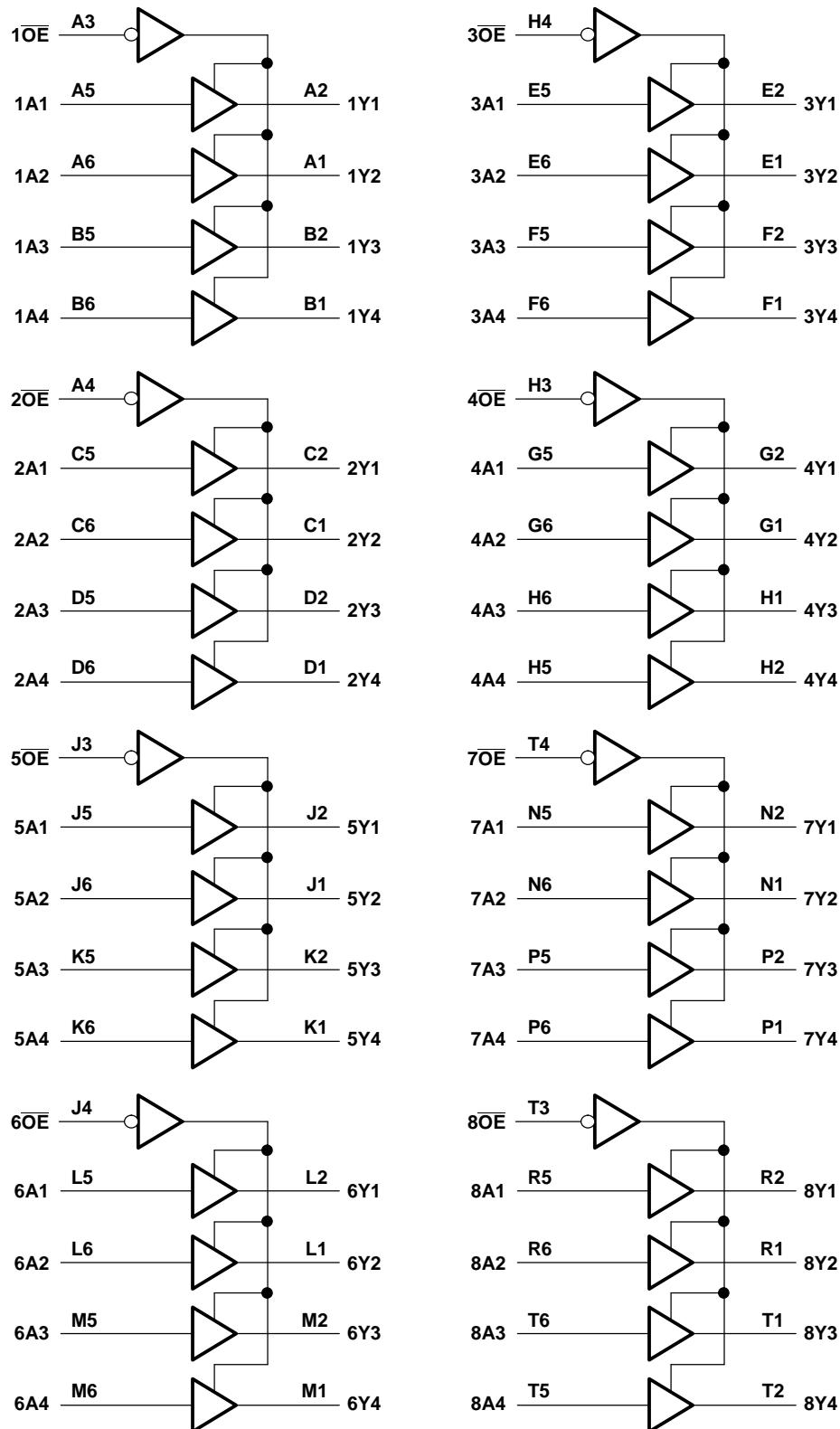
INPUTS		OUTPUT
$\overline{OE}$	A	Y
H	X	Z

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**32-BIT BUFFER/DRIVER**  
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**LOGIC DIAGRAM (POSITIVE LOGIC)**



**Absolute Maximum Ratings<sup>(1)</sup>**

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	3.6	V
$V_I$	Input voltage range <sup>(2)</sup>		-0.5	3.6	V
$V_O$	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>		-0.5	3.6	V
$V_O$	Output voltage range <sup>(2)</sup>		-0.5	$V_{CC} + 0.5$	V
$I_{IK}$	Input clamp current	$V_I < 0$		-50	mA
$I_{OK}$	Output clamp current	$V_O < 0$		-50	mA
$I_O$	Continuous output current			$\pm 20$	mA
	Continuous current through $V_{CC}$ or GND			$\pm 100$	mA
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>			40	°C/W
$T_{stg}$	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

**Recommended Operating Conditions<sup>(1)</sup>**

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		0.8	2.7	V
$V_{IH}$	High-level input voltage	$V_{CC} = 0.8$ V	$V_{CC}$		V
		$V_{CC} = 1.1$ V to 1.95 V	$0.65 \times V_{CC}$		
		$V_{CC} = 2.3$ V to 2.7 V	1.7		
$V_{IL}$	Low-level input voltage	$V_{CC} = 0.8$ V		0	V
		$V_{CC} = 1.1$ V to 1.95 V		$0.35 \times V_{CC}$	
		$V_{CC} = 2.3$ V to 2.7 V		0.7	
$V_I$	Input voltage		0	3.6	V
$V_O$	Output voltage	Active state	0	$V_{CC}$	V
		3-state	0	3.6	
$I_{OH}$	High-level output current	$V_{CC} = 0.8$ V		-0.7	mA
		$V_{CC} = 1.1$ V		-3	
		$V_{CC} = 1.4$ V		-5	
		$V_{CC} = 1.65$ V		-8	
		$V_{CC} = 2.3$ V		-9	
$I_{OL}$	Low-level output current	$V_{CC} = 0.8$ V		0.7	mA
		$V_{CC} = 1.1$ V		3	
		$V_{CC} = 1.4$ V		5	
		$V_{CC} = 1.65$ V		8	
		$V_{CC} = 2.3$ V		9	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 0.8$ V		20	ns/V
		$V_{CC} = 1.3$ V		15	
		$V_{CC} = 1.6$ V, 1.95 V, and 2.7 V		10	
$T_A$	Operating free-air temperature		-40	85	°C

(1) All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**SN74AUCH32244**  
**32-BIT BUFFER/DRIVER**  
**WITH 3-STATE OUTPUTS**

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**Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>OH</sub>	I <sub>OH</sub> = -100 $\mu$ A		0.8 V to 2.7 V	V <sub>CC</sub> - 0.1			V
	I <sub>OH</sub> = -0.7 mA		0.8 V		0.55		
	I <sub>OH</sub> = -3 mA		1.1 V		0.8		
	I <sub>OH</sub> = -5 mA		1.4 V		1		
	I <sub>OH</sub> = -8 mA		1.65 V		1.2		
	I <sub>OH</sub> = -9 mA		2.3 V		1.8		
V <sub>OL</sub>	I <sub>OL</sub> = 100 $\mu$ A		0.8 V to 2.7 V		0.2		V
	I <sub>OL</sub> = 0.7 mA		0.8 V		0.25		
	I <sub>OL</sub> = 3 mA		1.1 V		0.3		
	I <sub>OL</sub> = 5 mA		1.4 V		0.4		
	I <sub>OL</sub> = 8 mA		1.65 V		0.45		
	I <sub>OL</sub> = 9 mA		2.3 V		0.6		
I <sub>I</sub>	A or $\overline{OE}$ inputs	V <sub>I</sub> = V <sub>CC</sub> or GND	0 to 2.7 V		$\pm 5$	$\mu$ A	
I <sub>BHL</sub> <sup>(2)</sup>	V <sub>I</sub> = 0.35 V		1.1 V		10		$\mu$ A
	V <sub>I</sub> = 0.47 V		1.4 V		15		
	V <sub>I</sub> = 0.57 V		1.65 V		20		
	V <sub>I</sub> = 0.7 V		2.3 V		40		
I <sub>BHH</sub> <sup>(3)</sup>	V <sub>I</sub> = 0.8 V		1.1 V		-10		$\mu$ A
	V <sub>I</sub> = 0.9 V		1.4 V		-15		
	V <sub>I</sub> = 1.07 V		1.65 V		-20		
	V <sub>I</sub> = 1.7 V		2.3 V		-40		
I <sub>BHLO</sub> <sup>(4)</sup>	V <sub>I</sub> = 0 to V <sub>CC</sub>		1.3 V		75		$\mu$ A
			1.6 V		125		
			1.95 V		175		
			2.7 V		275		
I <sub>BHHO</sub> <sup>(5)</sup>	V <sub>I</sub> = 0 to V <sub>CC</sub>		1.3 V		-75		$\mu$ A
			1.6 V		-125		
			1.95 V		-175		
			2.7 V		-275		
I <sub>off</sub>	V <sub>I</sub> or V <sub>O</sub> = 2.7 V		0		$\pm 10$	$\mu$ A	
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND		2.7 V		$\pm 10$	$\mu$ A	
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND,	I <sub>O</sub> = 0	0.8 V to 2.7 V		40	$\mu$ A	
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND		2.5 V		3 4.5	pF	
C <sub>o</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND		2.5 V		4 7	pF	

(1) All typical values are at T<sub>A</sub> = 25°C.

(2) The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

(3) The bus-hold circuit can source at least the minimum high sustaining current at V<sub>IH</sub> min. I<sub>BHH</sub> should be measured after raising V<sub>IN</sub> to V<sub>CC</sub> and then lowering it to V<sub>IH</sub> min.

(4) An external driver must source at least I<sub>BHLO</sub> to switch this node from low to high.

(5) An external driver must sink at least I<sub>BHHO</sub> to switch this node from high to low.

## Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see [Figure 1](#))

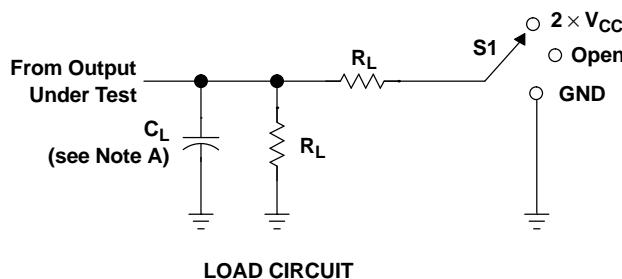
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V} \pm 0.1\text{ V}$		$V_{CC} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$			$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
$t_{pd}$	A	Y	5.4	0.8	2.8	0.6	1.9	0.7	1.3	1.8	0.5	1.8	ns
$t_{en}$	$\overline{OE}$	Y	8	1	4.4	0.7	2.6	0.8	1.4	2.5	0.6	1.9	ns
$t_{dis}$	$\overline{OE}$	Y	12	1.9	4.9	1	4.6	1.5	2.6	4	0.5	2	ns

## Operating Characteristics

$T_A = 25^\circ\text{C}$

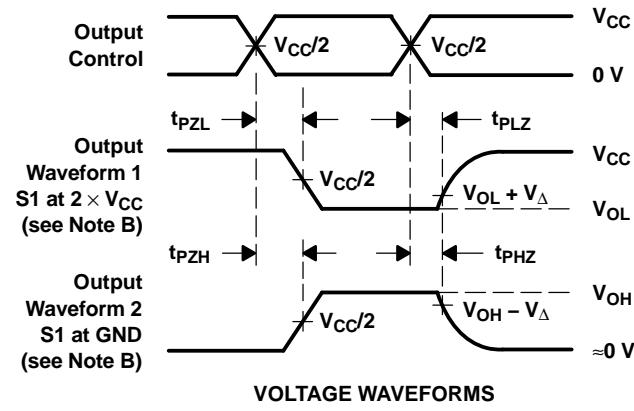
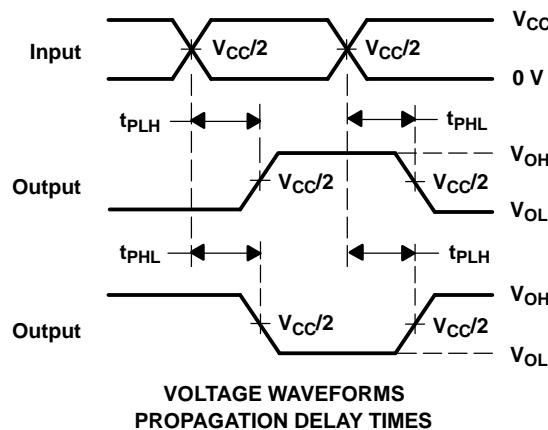
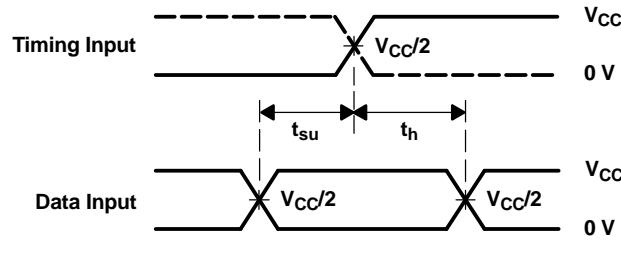
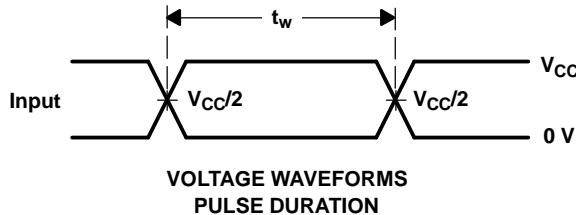
PARAMETER	TEST CONDITIONS	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V}$	$V_{CC} = 1.5\text{ V}$	$V_{CC} = 1.8\text{ V}$	$V_{CC} = 2.5\text{ V}$	UNIT	
		TYP	TYP	TYP	TYP	TYP		
$C_{pd}$ Power dissipation capacitance	Outputs enabled	$f = 10\text{ MHz}$	21	22	23	25	30	pF
	Outputs disabled		1	1	1	1	1	

### PARAMETER MEASUREMENT INFORMATION



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	2 $\times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	$C_L$	$R_L$	$V_{\Delta}$
0.8 V	15 pF	2 k $\Omega$	0.1 V
1.2 V $\pm$ 0.1 V	15 pF	2 k $\Omega$	0.1 V
1.5 V $\pm$ 0.1 V	15 pF	2 k $\Omega$	0.1 V
1.8 V $\pm$ 0.15 V	30 pF	1 k $\Omega$	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	500 $\Omega$	0.15 V



NOTES:

- $C_L$  includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50\Omega$ , slew rate  $\geq 1\text{ V/ns}$ .
- The outputs are measured one at a time, with one transition per measurement.
- $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
SN74AUCH32244GKER	NRND	LFBGA	GKE	96	1000	TBD	SNPB	Level-2-235C-1 YEAR	-40 to 85	MK244	
SN74AUCH32244ZKER	ACTIVE	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	-40 to 85	MK244	<b>Samples</b>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

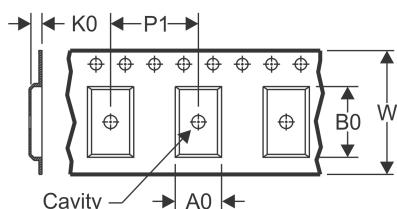
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

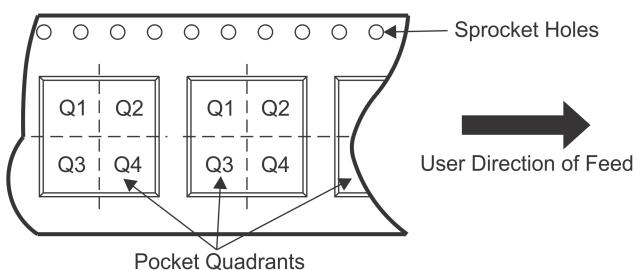
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**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUCH32244GKER	LFBGA	GKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1
SN74AUCH32244ZKER	LFBGA	ZKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1

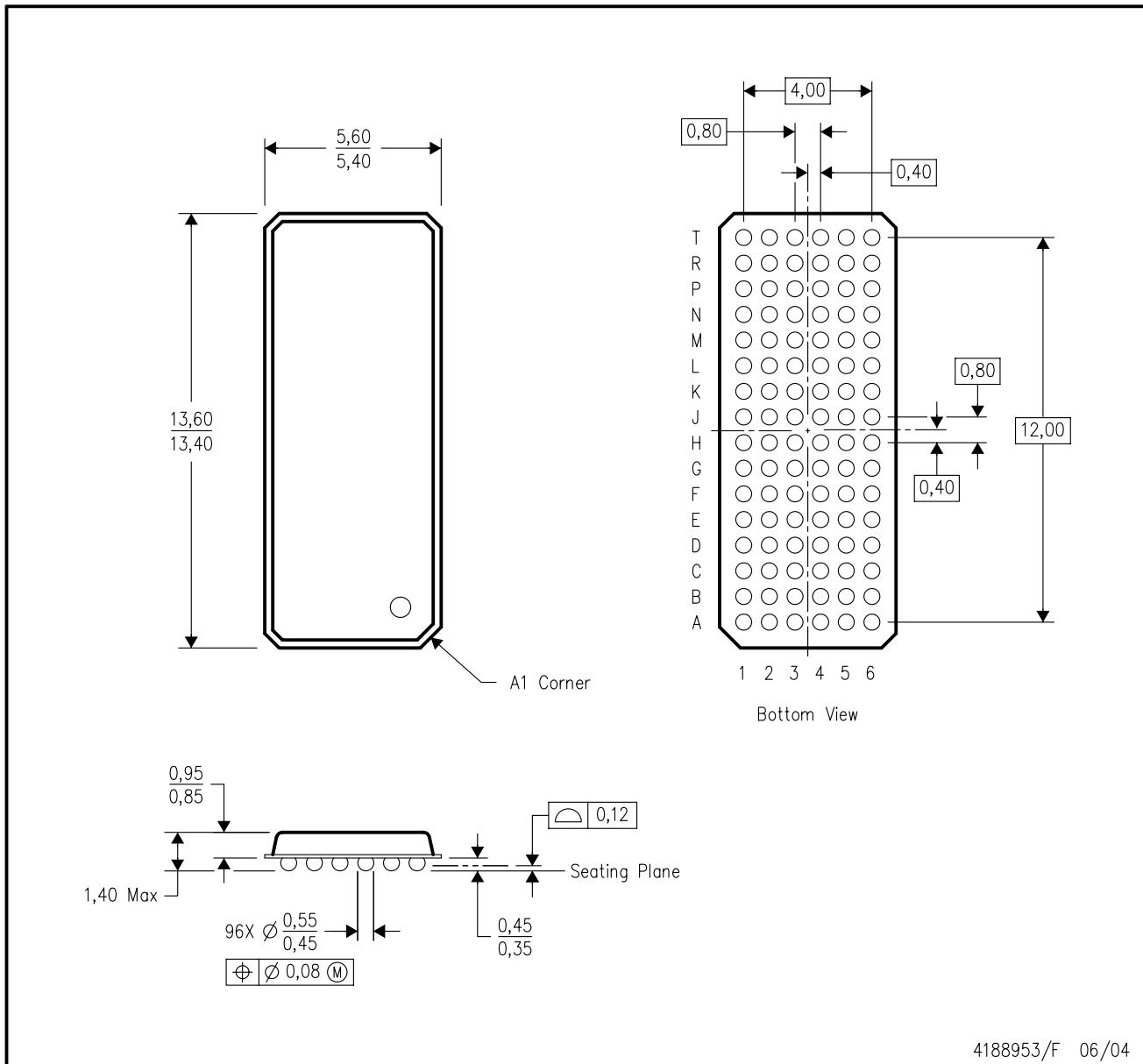
**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUCH32244GKER	LFBGA	GKE	96	1000	336.6	336.6	41.3
SN74AUCH32244ZKER	LFBGA	ZKE	96	1000	336.6	336.6	41.3

## GKE (R-PBGA-N96)

## PLASTIC BALL GRID ARRAY

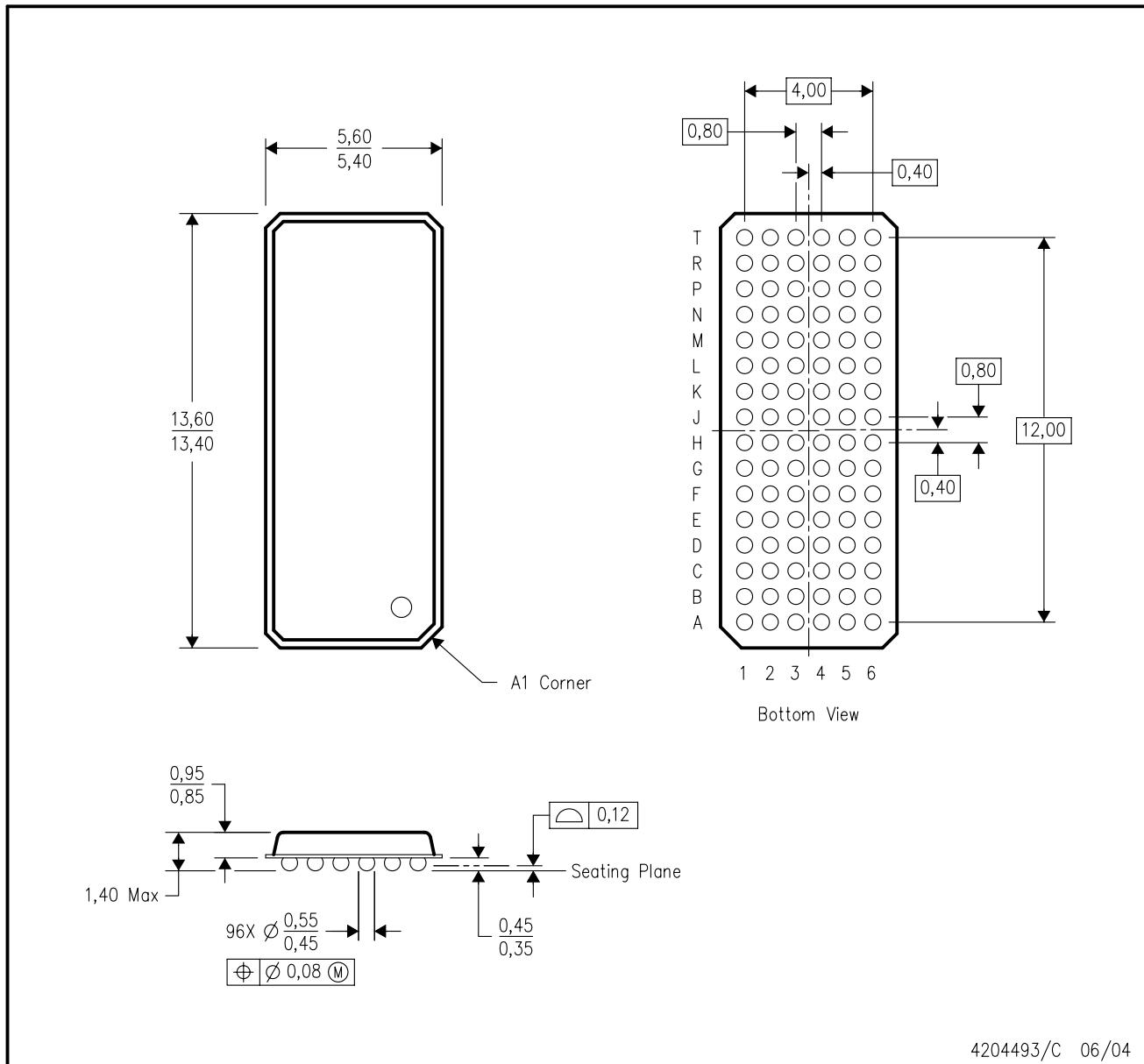


NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Falls within JEDEC MO-205 variation CC.
- This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.

## ZKE (R-PBGA-N96)

## PLASTIC BALL GRID ARRAY



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Falls within JEDEC MO-205 variation CC.
- This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).

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